#### **ABSOLUTE MAXIMUM RATINGS**

| IN to GND  | 0.3V to +30V                |
|--|-----------------------------|
| ABI, BATT, EN, POK to GND                            | 0.3V to +6V                 |
| ABO to GND   | 0.3V to $(V_{BATT} + 0.3V)$ |
| ISET to GND  | 0.3V to +4V                 |
| IN to BATT Continuous Current                        | 1A <sub>RMS</sub>           |
| Continuous Power Dissipation (T <sub>A</sub> = +70°C | C)                          |
| 8-Pin TDFN (derate 11.9mW/°C above -                 | +70°C)                      |
| (may altillay your DCD)                              | 0E2 Em\\\                   |

| BATT Short-Circuit Duration       | Continuous    |
|-----------------------------------|---------------|
| Operating Temperature Range       | 40°C to +85°C |
| Junction Temperature              | +150°C        |
| Storage Temperature Range         |               |
| Lead Temperature (soldering, 10s) | +300°C        |
|                                   |               |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{IN}=5V,\,V_{BATT}=4V,\,R_{\overline{POK}}=1M\Omega$  to BATT,  $\overline{EN}=0V,\,R_{ISET}=2.8k\Omega$  to GND,  $C_{BATT}=2.2\mu F,\,T_{A}=-40^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_{A}=+25^{\circ}C.$ ) (Note 1)

| PARAMETER  | CON  | IDITIONS                                      | MIN   | TYP   | MAX   | UNITS |  |
|--|--|---|-------|-------|-------|-------|--|
| Input Voltage Range                                  |  |   | 0     |       | 28    | V     |  |
| Input Operating Voltage Range                        |  |   | 4.25  |       | 6.80  | V     |  |
| Power-OK Threshold                                   | V <sub>IN</sub> - V <sub>BATT</sub> ,  | V <sub>IN</sub> rising                        |       | 40    |       | mV    |  |
| Tower-OK Threshold                                   | 10mV hysteresis (typ)  | V <sub>IN</sub> falling                       |       | 30    |       | 1110  |  |
| Overvoltage-Lockout Trip<br>Threshold                | V <sub>IN</sub> rising, 100mV hysteres   | sis (typ)                                     | 6.8   | 7     | 7.5   | V     |  |
|  | Constant-current charging  | mode (I <sub>BATT</sub> = 0A)                 |       | 0.8   | 1.35  |       |  |
| IN Input Current                                     | IC disabled (VEN = 5V)   |   |       | 0.23  | 0.50  |       |  |
| IN Input Current                                     | $V_{IN} = 4V$ ,  | $T_A = +25^{\circ}C$                          |       | 0.021 | 0.065 | mA    |  |
|  | $V_{BATT} = 4.2V$  | $T_A = +85^{\circ}C$                          |       | 0.021 |       |       |  |
| BATT Input Current                                   | V <sub>IN</sub> = 0 to 4V,<br>V <sub>BATT</sub> = 4.2V   |   |       | 1     | 10    | μА    |  |
|  | IC disabled  | sabled 3                                      |       |       | ]     |       |  |
| Pottory Pogulation Voltage                           | la . = = OA  | $T_A = 0$ °C to +85°C                         | 4.179 | 4.200 | 4.221 | V     |  |
| Battery Regulation Voltage                           | I <sub>BATT</sub> = 0A   | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | 4.158 | 4.200 | 4.242 |       |  |
| Minimum BATT Bypass<br>Capacitance                   |  |   |       | 2.2   |       | μF    |  |
|  | $V_{BATT} = 3.5V$ $V_{BATT} = 3.5V$ ,  | $T_A = 0$ °C to +85°C                         | 524   | 570   | 616   | - mA  |  |
| Foot Charge Current                                  |  | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | 485   | 570   | 656   |       |  |
| Fast-Charge Current                                  |  | $T_A = 0$ °C to +85°C                         | 89    | 107   | 125   |       |  |
|  | $R_{ISET} = 14k\Omega$   | $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ | 80    | 107   | 134   |       |  |
| Prequalification Charge Current                      | Percentage of the fast-charge current, V <sub>BATT</sub> = 2.2V, T <sub>A</sub> = 0°C to +85°C |   | 4     | 10    | 15    | %     |  |
| Die Temperature Regulation<br>Threshold              |  |   |       | +115  |       | °C    |  |
| V <sub>BATT</sub> Prequalification Threshold Voltage | V <sub>BATT</sub> rising, 100mV hysteresis (typ)   |   | 2.3   | 2.5   | 2.7   | V     |  |
| Current-Sense Amplifier Gain (IBATT to IJSET)        | I <sub>BATT</sub> = 570mA  |   |       | 877.2 |       | μΑ/Α  |  |

2 \_\_\_\_\_\_ *M*/XI/N

### **ELECTRICAL CHARACTERISTICS (continued)**

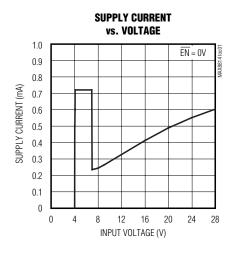
 $(V_{IN}=5V,\,V_{BATT}=4V,\,R_{\overline{POK}}=1M\Omega$  to BATT,  $\overline{EN}=0V,\,R_{ISET}=2.8k\Omega$  to GND,  $C_{BATT}=2.2\mu F,\,T_{A}=-40^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_{A}=+25^{\circ}C$ .) (Note 1)

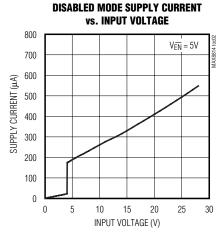
| PARAMETER                                  | CON   | DITIONS                | MIN                      | TYP   | MAX | UNITS |
|--|---|------------------------|--------------------------|-------|-----|-------|
| Regulator Dropout Voltage (VIN - VBATT)    | V <sub>BATT</sub> = 4.1V, I <sub>BATT</sub> = 425mA |                        |                          | 240   | 500 | mV    |
| EN Logic-Input Low Voltage                 | 4.25V < V <sub>IN</sub> < 6.5V                      |                        |                          |       | 0.4 | V     |
| EN Logic-Input High Voltage                | 4.25V < V <sub>IN</sub> < 6.5V                      |                        | 1.3                      |       |     | V     |
| EN and ABI Internal Pulldown<br>Resistance |   |                        | 100                      | 200   | 400 | kΩ    |
| ABI Logic-Input Low Voltage                | $V_{IN} = 0V$                                       |                        |                          |       | 0.4 | V     |
| ABI Logic-Input High Voltage               | $V_{IN} = 0V$                                       |                        | 1.3                      |       |     | V     |
| ABO Output Low Voltage                     | I <sub>ABO</sub> (SINK) = 1mA                       |                        |                          |       | 0.4 | V     |
| ABO Output High Voltage                    | IABO (SOURCE) = 1mA                                 |                        | V <sub>BATT</sub> - 0.4V |       |     | V     |
| POK Output Low Voltage                     | $\overline{POK} = 5mA$                              |                        |                          |       | 0.4 | V     |
| POK Output High Leakage                    | Vacus E EV  | T <sub>A</sub> = +25°C |                          | 0.001 | 1   |       |
| Current                                    | $V_{\overline{POK}} = 5.5V$                         | T <sub>A</sub> = +85°C |                          | 0.002 |     | μΑ    |

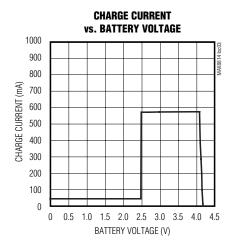
**Note 1:** Specifications are 100% production tested at T<sub>A</sub> = +25°C. Limits over the operating temperature range are guaranteed by design and characterization.

## Typical Operating Characteristics

 $(V_{IN}=5V,V_{BATT}=4V,R_{\overline{POK}}=1M\Omega$  to BATT,  $\overline{EN}=0V,R_{ISET}=2.8k\Omega$  to GND,  $C_{BATT}=2.2\mu F,T_{A}=-40^{\circ}C$  to  $+85^{\circ}C$ , unless otherwise noted. Typical values are at  $T_{A}=+25^{\circ}C$ .)



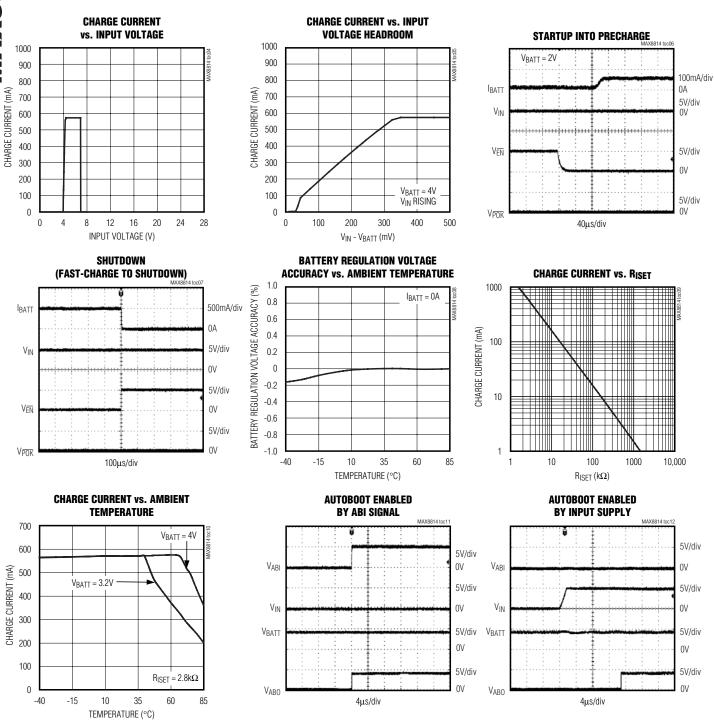




### \_Typical Operating Characteristics (continued)

MIXIM

 $(V_{IN}=5V, V_{BATT}=4V, R_{\overline{POK}}=1M\Omega$  to BATT,  $\overline{EN}=0V, R_{ISET}=2.8k\Omega$  to GND,  $C_{BATT}=2.2\mu F, T_A=-40^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A=+25^{\circ}C$ .)



## **Pin Description**

| PIN | NAME | FUNCTION   |
|-----|------|--|
| 1   | IN   | Input Supply Voltage. Bypass IN to GND with a 1µF or larger ceramic capacitor to minimize line noise and maximize input transient rejection.   |
| 2   | GND  | Ground. Connect GND and the exposed paddle to a large copper ground plane for maximum power dissipation. Connect GND to the exposed paddle directly under the IC.  |
| 3   | ISET | Charge-Current Program and Fast-Charge Current Monitor. Output current from ISET is 877.2µA per ampere of battery charging current. Set the charging current by connecting a resistor (R2 in Figure 3) from ISET to GND. IFAST-CHARGE = 1596V / RISET. To configure the MAX8814 as a USB charger, see Figure 4.                                    |
| 4   | ABI  | Autobooting External Input. See the <i>Autobooting Assistant</i> section and Table 1 for autobooting conditions. ABI is pulled to GND through an internal 200k $\Omega$ resistor.  |
| 5   | ABO  | Autobooting Logic Output. See the <i>Autobooting Assistant</i> section and Table 1 for autobooting conditions.   |
| 6   | ĒN   | Logic-Level Enable Input. Drive $\overline{\text{EN}}$ high to disable charger. Drive $\overline{\text{EN}}$ low or leave unconnected for normal operation. $\overline{\text{EN}}$ has an internal 200k $\Omega$ pulldown resistor.  |
| 7   | POK  | Input-Voltage Status Indicator. Connect a $1M\Omega$ pullup resistor from $\overline{POK}$ to an external system supply. $\overline{POK}$ is an open-drain output that asserts low when $V_{IN} > 4.25V$ and $(V_{IN} - V_{BATT}) \ge 40mV$ . If $V_{BATT} \ge (V_{IN} - 40mV)$ , the IC is shut down and $\overline{POK}$ becomes high impedance. |
| 8   | BATT | Battery Connection. Bypass BATT to GND with a minimum of 2.2µF of capacitor.   |
| _   | EP   | Exposed Paddle. Connect the exposed paddle to a large ground plane for maximum power dissipation. Connect GND to the exposed paddle directly under the IC.   |

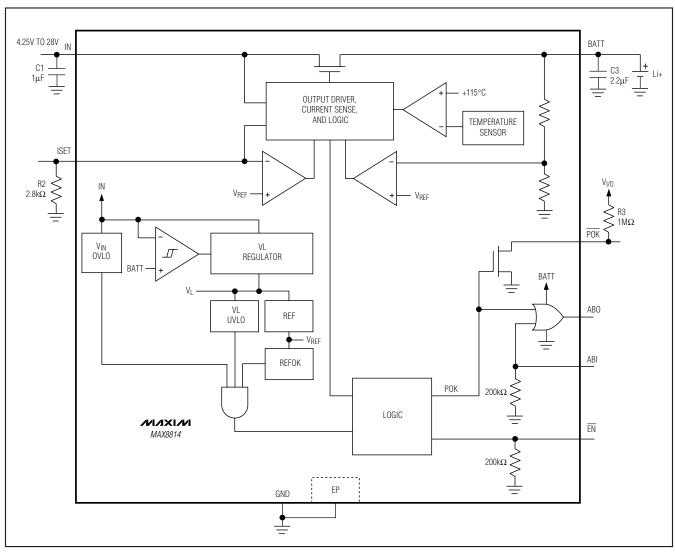


Figure 1. Functional Diagram

## **Detailed Description**

The MAX8814 charger uses voltage, current, and thermal-control loops to charge a single Li+ cell and protect the battery (Figure 1). When a Li+ battery with a cell voltage below 2.5V is inserted, the MAX8814 charger enters the prequalification stage where it precharges that cell with 10% of the user-programmed fast-charge current (Figure 2). When the battery voltage exceeds 2.5V, the charger soft-starts as it enters the fast-charge stage. In the MAX8814, the fast-charge current level is programmed through a resistor from ISET to GND. As the battery voltage approaches 4.2V,

the charging current is reduced. Once the battery voltage reaches 4.2V, the IC then enters a constant voltage regulation mode to maintain the battery at full charge.

#### **Thermal Regulation**

The thermal-regulation loop limits the MAX8814 die temperature to +115°C by reducing the charge current as necessary. This feature not only protects the IC from overheating, but also allows a higher charge current without risking damage to the IC.

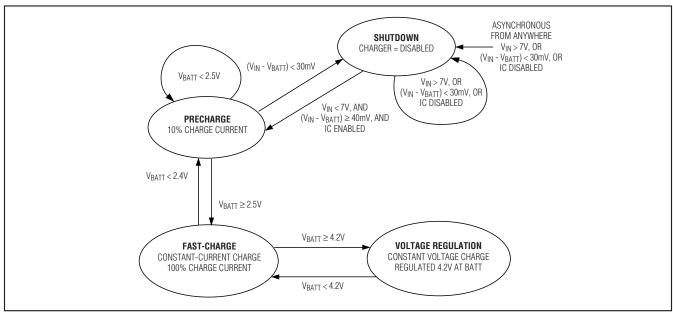


Figure 2. Charge-State Diagram

### **Charger Enable Input**

The MAX8814 contains an active-low logic input  $(\overline{EN})$  used to enable the charger. Drive  $\overline{EN}$  low, leave unconnected, or connect to GND to enable the charger-control circuitry. Drive  $\overline{EN}$  high to disable the charger-control circuitry.  $\overline{EN}$  has an internal 200k $\Omega$  pull-down resistor.

### **POK** Output

The open-drain  $\overline{POK}$  output asserts low when  $V_{IN} \ge 4.25V$  and  $(V_{IN} - V_{BATT}) \ge 40 \text{mV}$  (typ,  $V_{IN}$  rising).  $\overline{POK}$  requires an external pullup resistor (1M $\Omega$  typ) to an external power supply.  $\overline{POK}$  is high impedance when  $V_{BATT} \ge (V_{IN} - 40 \text{mV})$ .

#### **Autobooting Assistant**

The MAX8814 contains an autobooting assistant circuit that generates an enable signal for system booting (ABO). The booting assistant functions as an internal "OR" gate (Figure 1). The first input is dependent on the input voltage (VIN), and the second input is an external signal applied to ABI. The first input (POK) is driven high once  $V_{IN} \ge 4.25V$  and  $(V_{IN} - V_{BATT}) \ge 40\text{mV}$  (typ,  $V_{IN}$  rising).

The second input signal (ABI) is driven by an external source. ABI enables an autoboot signal (ABO high) when a battery is connected at BATT and is independent of  $\overline{POK}$ . If  $\overline{POK}$  is pulled low, the booting assistant always drives ABO high, regardless of ABI (see Table 1). ABI is pulled to GND through an internal 200k $\Omega$  resistor.

## Table 1. ABO and POK States

| ABI  | BATT        | POK  | CHARGER STATE                  | ABO  |
|------|-------------|--|--------------------------------|------|
| Low  | Present     | Hi-Z                                       | Shutdown                       | Low  |
| High | Present     | Hi-Z                                       | Shutdown                       | High |
| Х    | Not present | Low  | Fast-charge/voltage regulation | High |
| Х    | Present     | Present Low Fast-charge/voltage regulation |                                | High |

X = Don't care.

If ABI is driven externally, a RC filter (R1 and C2 of Figure 3) is required for ESD protection and noise filtering. If ABI is supplied by a system's internal GPIO, or logic, the RC filter is not required.

#### Soft-Start

The soft-start algorithm activates when entering fast-charge mode. In the MAX8814, when the prequalification state is complete ( $V_{BATT} \ge 2.5V$ ), the charging current ramps up in 250µs to the full charging current. This reduces the inrush current on the input supply.

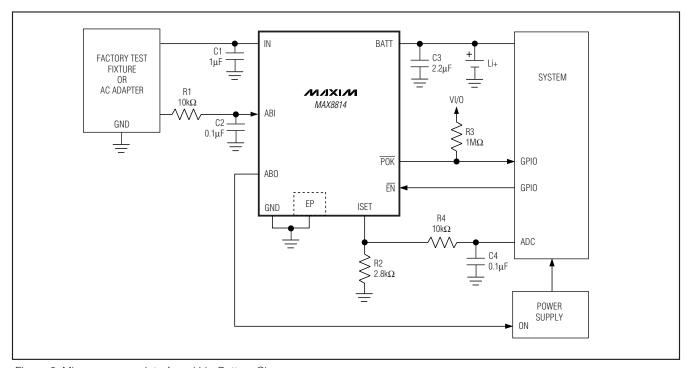


Figure 3. Microprocessor-Interfaced Li+ Battery Charger

### Applications Information

#### **Charge-Current Selection**

The maximum charging current is programmed by an external resistor connected from ISET to GND (RISET). Calculate RISET as follows:

$$R_{ISET} = \frac{1596V}{I_{FAST-CHARGE}}$$

where IFAST-CHARGE is in amperes and RISET is in ohms. ISET can be used to monitor the fast-charge current level. The output current from ISET is 877.2μA per ampere of charging current. The output voltage at ISET is proportional to the charging current:

$$V_{ISET} = \frac{I_{CHARGE} \times R_{ISET}}{1140}$$

The voltage at ISET is nominally 1.4V at the selected fast-charge current and falls with charging current as the cell becomes fully charged or as the thermal-regulation circuitry activates.

### **Capacitor Selection**

Connect a ceramic capacitor from BATT to GND for proper stability. Use a 2.2 $\mu$ F X5R ceramic capacitor for most applications. Connect a 1 $\mu$ F ceramic capacitor from IN to GND. Use a larger input bypass capacitor for high charging currents to reduce supply noise.

#### **Thermal Considerations**

The MAX8814 is available in a thermally enhanced TDFN package with an exposed paddle. Connect the exposed paddle to a large copper ground plane to provide a thermal contact between the device and the circuit board for increased power dissipation. The exposed paddle transfers heat away from the device, allowing the IC to charge the battery with maximum current, while minimizing the increase in die temperature.

### **DC Input Sources**

The MAX8814 operates from a well-regulated DC source. The full charging input voltage range is 4.25V to 7V. The device can withstand up to 28V on the input without damage to the IC. If  $V_{\rm IN}$  is greater than 7V, the internal overvoltage-protection circuitry disables charging until the input falls below 7V. An appropriate power supply must provide at least 4.25V at the desired peak charging current.

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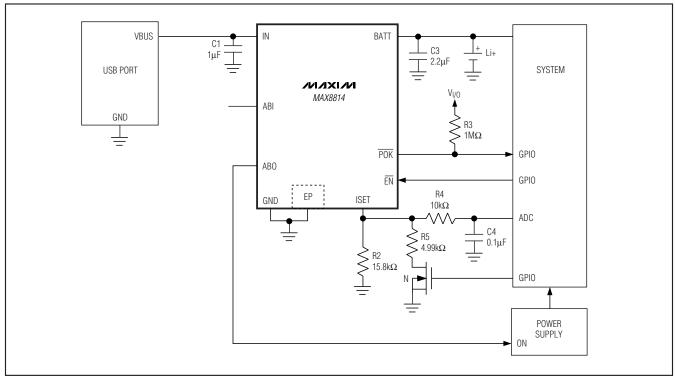


Figure 4. USB Battery Charger

#### **Application Circuits**

#### Microprocessor-Interfaced Charger

Figure 3 shows the MAX8814 as a microprocessor-cooperated Li+ battery charger. The MAX8814 begins charging the battery when  $\overline{\text{EN}}$  is low. The microprocessor can drive  $\overline{\text{EN}}$  high to disable the charger. The MAX8814 generates a  $\overline{\text{POK}}$  signal to indicate the presence of an input supply. By monitoring VISET, the system can measure the charging current and decide when to terminate the charge.

#### **USB-Powered Li-Ion Charger**

The universal serial bus (USB) provides a high-speed serial communication port as well as power for the remote device. The MAX8814 can be configured to charge a battery at the highest current possible from the host port. Figure 4 shows the MAX8814 as a USB battery charger. To make the circuit compatible with either 100mA or 500mA USB ports, the circuit initializes at 100mA charging current. The microprocessor then enumerates the host to determine its current capability. If the host port is capable, the charging current is increased to 425mA to avoid exceeding the 500mA USB specification.

### **Layout and Bypassing**

Place the input and output capacitors as close as possible to the IC. Provide a large copper ground plane to allow the exposed paddle to sink heat away from the IC. Connect the battery to BATT as close as possible to the IC to provide accurate battery voltage sensing. Make all high-current traces short and wide to minimize voltage drops. A sample layout is available in the MAX8814 Evaluation Kit to speed designs.

Chip Information

PROCESS: BICMOS

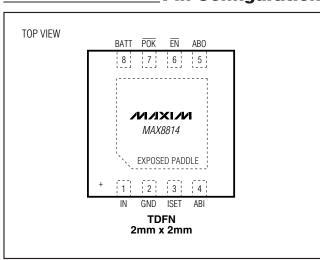
/N/X|/V| \_\_\_\_\_\_\_ 9

## **Pin Configuration**



For the latest package outline information, go to **www.maxim-ic.com/packages**.

| PACKAGE TYPE | PACKAGE CODE | DOCUMENT NO.   |
|--------------|--------------|----------------|
| 8 TDFN       | T822+2       | <u>21-0168</u> |



## **Revision History**

| REVISION<br>NUMBER | REVISION<br>DATE | DESCRIPTION   | PAGES<br>CHANGED |
|--------------------|------------------|---|------------------|
| 0                  | 10/07            | Initial release   |                  |
| 1                  | 2/08             | Changed OVP (min) to 6.8V from 6.5V with 6 sigma without silicon change | 2                |
| 2                  | 3/08             | Changed Input Operating Voltage maximum range from 6.8V to 6.5V.        | 1                |

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\_ 11